



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

P-Channel Silicon MOSFET

CPH6355 — General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS(on)1}=130m\Omega$ (typ.)
- 4V drive
- Halogen free compliance

Specifications

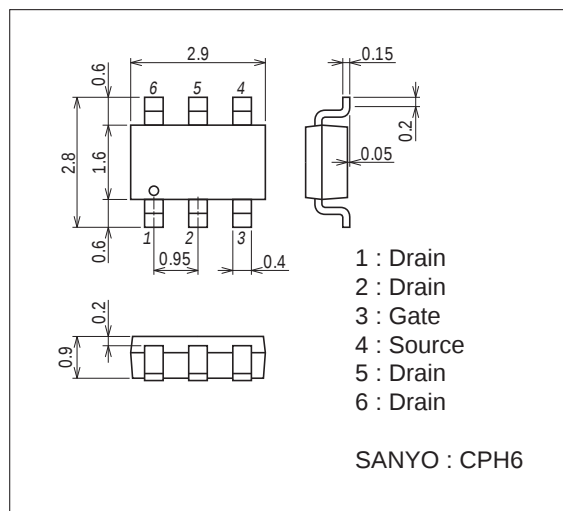
Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DS}		-30	V
Gate-to-Source Voltage	V_{GS}		± 20	V
Drain Current (DC)	I_D		-3	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-12	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate ($1500mm^2 \times 0.8mm$)	1.6	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Package Dimensions

unit : mm (typ)

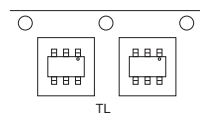
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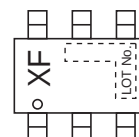
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

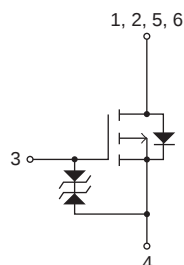
Packing Type: TL



Marking



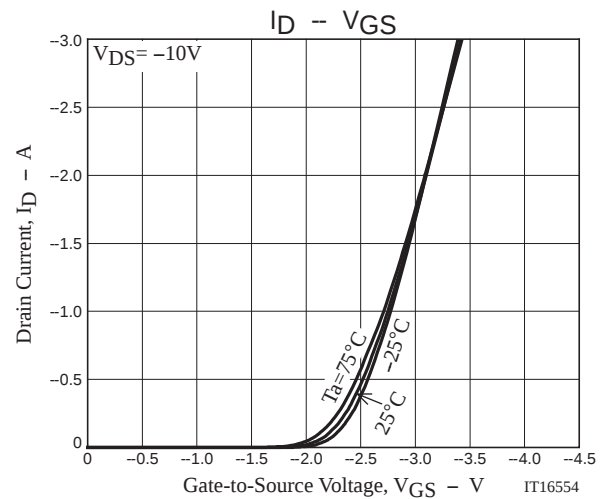
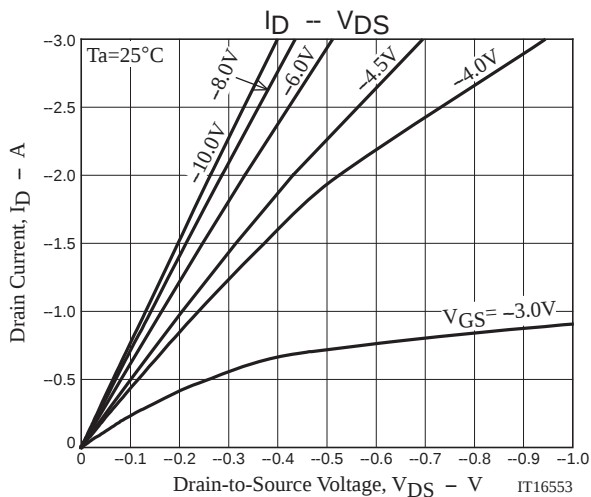
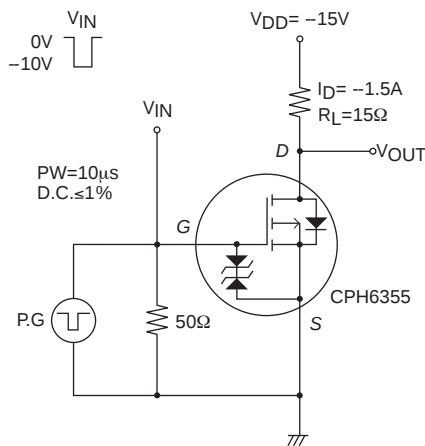
Electrical Connection

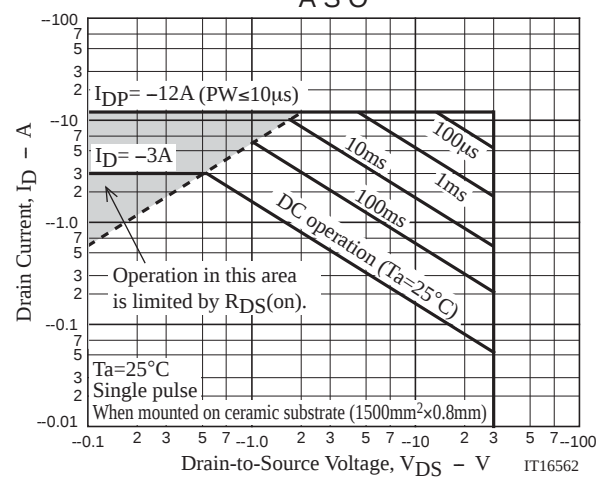
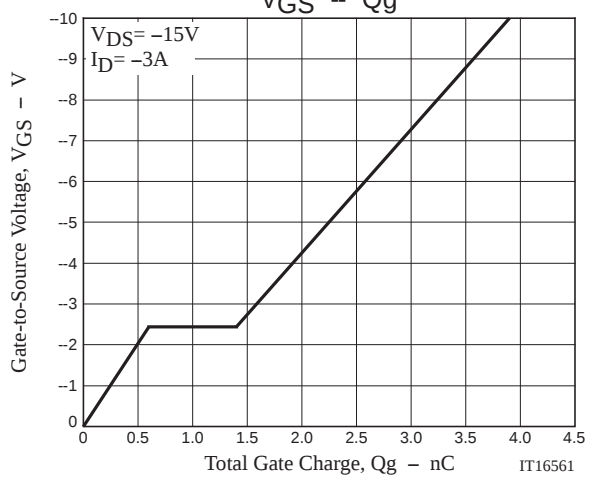
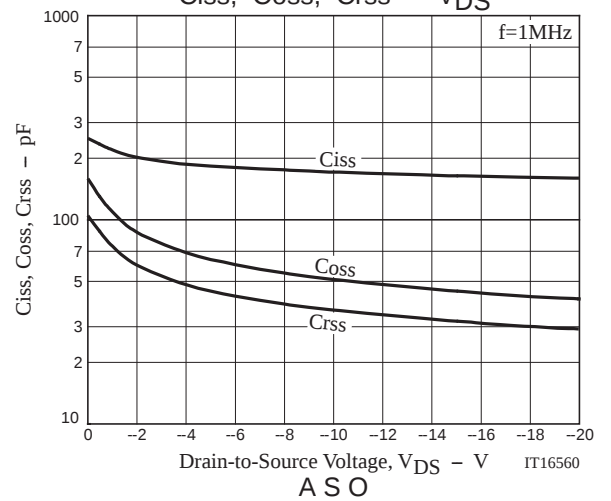
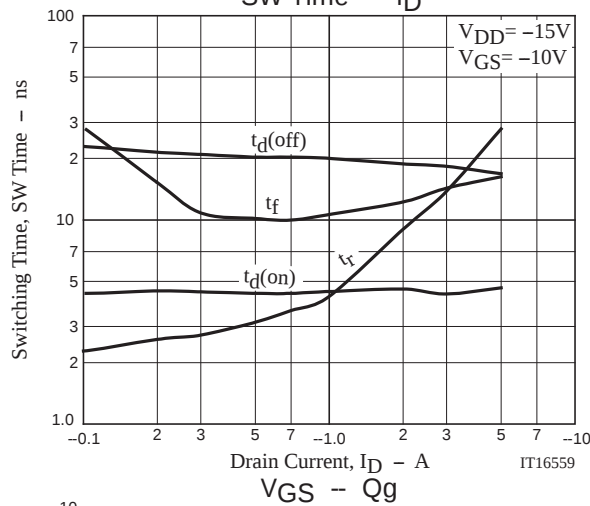
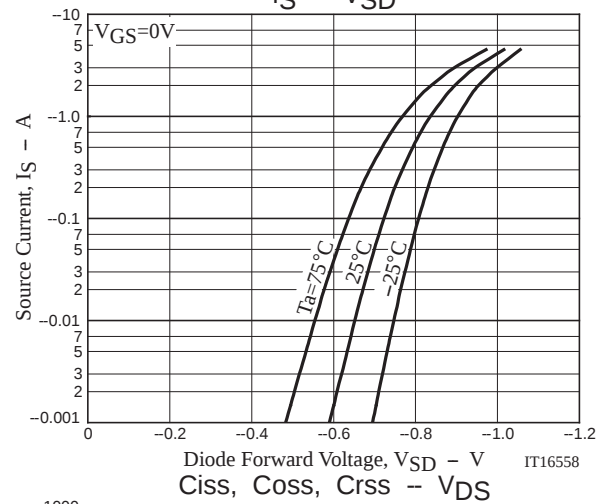
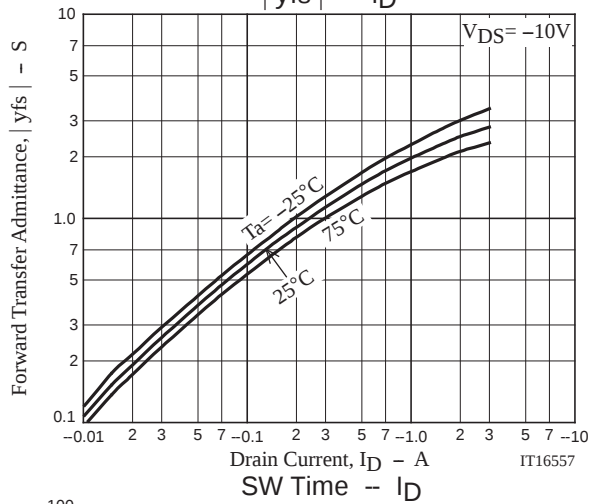
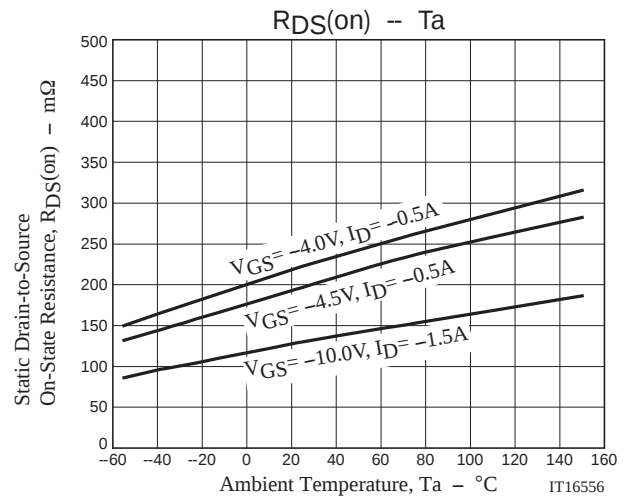
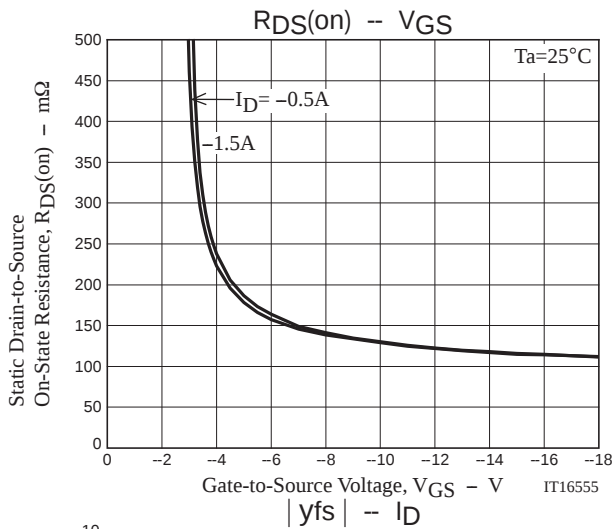


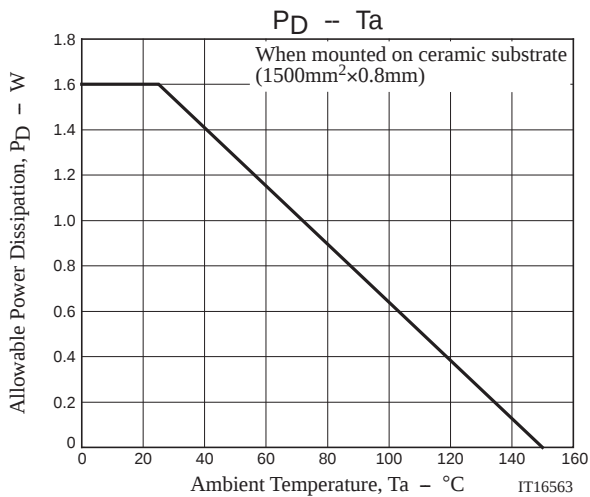
Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=-1\text{mA}$, $V_{GS}=0\text{V}$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30\text{V}$, $V_{GS}=0\text{V}$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}$, $V_{DS}=0\text{V}$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-10\text{V}$, $I_D=-1\text{mA}$	-1.2		-2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10\text{V}$, $I_D=-1.5\text{A}$		2.3		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-1.5\text{A}$, $V_{GS}=-10\text{V}$		130	169	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=-0.5\text{A}$, $V_{GS}=-4.5\text{V}$		197	276	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=-0.5\text{A}$, $V_{GS}=-4\text{V}$		223	313	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=-10\text{V}$, $f=1\text{MHz}$		172		pF
Output Capacitance	C_{oss}			51		pF
Reverse Transfer Capacitance	C_{rss}			36		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		4.6		ns
Rise Time	t_r			6.6		ns
Turn-OFF Delay Time	$t_d(off)$			19.4		ns
Fall Time	t_f			11.4		ns
Total Gate Charge	Q_g	$V_{DS}=-15\text{V}$, $V_{GS}=-10\text{V}$, $I_D=-3\text{A}$		3.9		nC
Gate-to-Source Charge	Q_{gs}			0.6		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			0.8		nC
Diode Forward Voltage	V_{SD}	$I_S=-3\text{A}$, $V_{GS}=0\text{V}$		-0.95	-1.5	V

Switching Time Test Circuit







Note on usage : Since the CPH6355 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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